Shunt Regulator

# HITACHI

ADE-204-070 (Z)

Preliminary Rev.0 Sep. 2001

#### Description

The HA17431H series is a family of voltage referenced shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The HA17431H series products are provided in a wide range of packages; TO-92 insertion mounting packages and MPAK-5 (5 pin), MPAK (3 pin), UPAK surface mounting packages are available. The on-chip high-precision reference voltage source can provide  $\pm 1\%$  accuracy, which have a V<sub>KA</sub> max of 36 volts.

#### Features

- The reference voltage provide 2.500 V  $\pm 1\%$  at Ta = 25°C
- The reference voltage has a low temperature coefficient
- The MPAK-5 (5 pin), MPAK (3 pin) and UPAK miniature packages are optimal for use on high mounting density circuit boards

### **Block Diagram**





## **Application Circuit Example**



#### **Ordering Information**

Industrial use HA17431HLP MPAK-5 -20 to +85°C   HA17431HP TO-92 -20 to +85°C -20 to +85°C	Item		Package	Temp. Range
HA17431HP TO-92	Industrial use	HA17431HLP	MPAK-5	–20 to +85°C
		HA17431HP	TO-92	
HA17431HUP UPAK		HA17431HUP	UPAK	
HA17432HUP		HA17432HUP		
HA17431HLTP MPAK		HA17431HLTP	MPAK	
HA17432HLTP		HA17432HLTP		

### **Pin Arrangement**



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#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

		Ratings					
Item	Symbol	HA17431HLP	HA17431HP	HA17431HUP/ HA17432HUP	HA17431HLTP/ HA17432HLTP	Unit	Notes
Cathode voltage	$V_{\kappa A}$	36	36	36	36	V	1
Continuous cathode current	Ι <sub>κ</sub>	–50 to +50	-50 to +50	-50 to +50	–50 to +50	mA	
Reference input current	Iref	-0.05 to +6	-0.05 to +6	-0.05 to +6	-0.05 to +6	mA	
Power dissipation	Ρ <sub>τ</sub>	150 * <sup>2</sup>	500 * <sup>3</sup>	800 *4	150 * <sup>2</sup>	MW	
Operating temperature range	Topr	-20 to +85	-20 to +85	–20 to +85	–20 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	–55 to +150	°C	

Notes: 1. Voltages are referenced to anode.

2. Ta  $\leq$  25°C. If Ta > 25°C, derate by 1.2 mW/°C.

3. Ta  $\leq$  25°C. If Ta > 25°C, derate by 4.0 mW/°C.

4. 15 mm  $\times$  25 mm  $\times$  t0.7mm alumina ceramic board,Ta  $\leq$  25°C. If Ta > 25°C, derate by 6.4 mW/°C.

#### **Electrical Characteristics**

 $(Ta = 25^{\circ}C, I_{\kappa} = 10 \text{ mA})$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	Notes
Reference voltage	Vref	2.475	2.500	2.525	V	$V_{KA} = Vref$	
Reference voltage temperature deviation	Vref(dev)	—	10	—	mV	$V_{KA} = Vref,$ Ta = -20°C to +85°C	1
Reference voltage temperature coefficient	∆Vref/∆Ta	_	±30		ppm/°C	V <sub>KA</sub> = Vref, 0°C to 50°C gradient	
Reference voltage regulation	$\Delta \text{Vref} / \Delta \text{V}_{\text{\tiny KA}}$	_	2.0	3.7	mV/V	$V_{KA} = Vref to 36 V$	
Reference input current	Iref	_	0.6	3	μA	$R_1 = 10 \text{ k}\Omega, R_2 = \infty$	
Reference current temperature deviation	Iref(dev)	_	0.5	_	μA	$R_1$ = 10 kΩ, $R_2$ = ∞, Ta = -20°C to +85°C	
Minimum cathode current	Imin	_	0.06	0.2	mA	$V_{KA} = Vref$	2
Off state cathode current	loff	—	0.001	1.0	μA	$V_{KA} = 36 V$ , $Vref = 0 V$	
Dynamic impedance	Z <sub>KA</sub>	—	0.2	0.5	Ω	$V_{_{KA}} = Vref,$ $I_{_{K}} = 1 mA to 50 mA$	
Notes: 1. Vref(dev	) = Vref(max)	– Vref(miı	า)				



2. Imin is given by the cathode current at  $Vref = Vref_{(IK=10mA)} - 15 \text{ mV}.$ 

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## MPAK-5 (5 pin), MPAK (3 pin) and UPAK Marking Patterns

The marking patterns shown below are used on MPAK-5, MPAK and UPAK products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

Product	(1)	(2)
HA17431HLP	4	Н
HA17431HUP	4	U
HA17432HUP	4	W
HA17431HLTP	3	С
HA17432HLTP	3	D

2. The letters (1) and (2) show the product specific mark pattern.

- 3. The letter (3) shows the production year code (the last digit of the year) for UPAK products.
- 4. The bars (a), (b) and (c) show a production year code for MPAK-5 and MPAK products as shown below. After 2009 the code is repeated every 8 years.

			•					
Year	2001	2002	2003	2004	2005	2006	2007	2008
(a)	None	None	None	None	Bar	Bar	Bar	Bar
(b)	None	None	Bar	Bar	None	None	Bar	Bar
(c)	None	Bar	None	Bar	None	Bar	None	Bar

5. The letter (4) shows the production month code (see table below).

Production month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Marked code	А	В	С	D	Е	F	G	Н	J	К	L	М

6. The letter (5) shows manufacturing code. For UPAK products.

#### **Application Examples**

As shown in figure 1, this IC operates as an inverting amplifier, with the REF pin as input pin. The openloop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 0.6  $\mu$ A Typ. The output impedance of the output pin K (cathode) is defined as dynamic impedance  $Z_{KA}$ , and  $Z_{KA}$  is low (0.2  $\Omega$ ) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.



Figure 1 Operation Diagram

No.	Application Example	Description			
1	Reference voltage generation circuit Vin O	This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_{\kappa} \ge 0.2$ mA.			
		Output is fixed at Vout $\cong$ 2.5 V.			
		The external capacitor $C_{_{L}}$ ( $C_{_{L}} \ge 3.3 \ \mu F$ ) is used to prevent oscillation in normal applications.			
2	Variable output shunt regulator circuit	This is circuit 1 above with variable output provided.			
	VinO_/// • • OVout R s lref R <sub>1</sub> S   K	Here, Vout $\cong$ 2.5 V $\times \frac{(R_1 + R_2)}{R_2}$			
	$\begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	Since the reference input current Iref = 0.6 $\mu$ A Typ flows through R <sub>1</sub> , resistance values are chosen to allow the resultant voltage drop to be ignored.			
	777				

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#### **Application Hints**

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#### Application Hints (cont.)

Cf

Gain G =

No.	Application Example
3	Single power supply inverting comparator circuit
	QV <sub>CC</sub> ≤ ₽.
4	AC amplifier circuit

Cin R<sub>3</sub>

R<sub>1</sub> R<sub>2</sub> // R<sub>3</sub>

 $R_2$ 

oVcc

K

REF

(DC gain)

R

0

Vout

--0 GND Description

This is an inverting type comparator with an input threshold voltage of approximately 2.5 V. Rin is the REF pin protection resistance, with a value of several  $k\Omega$  to several tens of  $k\Omega$ .

 $R_{_L}$  is the load resistance, selected so that the cathode current  $I_{_{\rm K}} \ge 0.2$  mA when Vout is low.

Condition	Vin	Vout	IC
C1	Less then 2.5 V	V <sub>CC</sub> (V <sub>OH</sub> )	OFF
C2	2.5 V or more	Approx. 2 V (V <sub>OL</sub> )	ON

This is an AC amplifier with voltage gain  $G = -R_1 / (R_2//R_3)$ . The input is cut by capacitance Cin, so that the REF pin is driven by the AC input signal, centered on 2.5  $V_{nc}$ .

 $\rm R_{_2}$  also functions as a resistance that determines the DC cathode potential when there is no input, but if the input level is low and there is no risk of Vout clipping to  $\rm V_{cc},$  this can be omitted.

To change the frequency characteristic, Cf should be connected as indicated by the dotted line.



This circuit performs control on the secondary side of a transformer, and is often used with a switching power supply that employs a photocoupler for offlining.

The output voltage (between V+ and V–) is given by the following formula:

$$Vout \cong 2.5 \ V \times \frac{(R_1 + R_2)}{R_2}$$

In this circuit, the gain with respect to the Vout error is as follows:

$$G = \frac{R_2}{(R_1 + R_2)} \times \left[ \frac{HA17431H}{loop gain} \right] \times \left[ \frac{Photocoupler}{total gain} \right]$$

As stated earlier, the HA17431H open-loop gain is 50 to 60 dB.

#### Application Hints (cont.)

#### No. Application Example

7

8

0

V<sub>CC</sub>

GND

GND





Discharge type constant current circuit

Q

Rs

ΙL

Load

777

Rs

R

2.5 V

2.5 V

 $\mathbb{A}$ 

#### Description

This is a 3-pin regulator with a discrete configuration, in which the output voltage

Vout = 2.5 V × 
$$\frac{(R_2 + R_3)}{R_3}$$

 $\rm R_1$  is a bias resistance for supplying the HA17431H cathode current and the output transistor Q base current.

This circuit supplies a constant current of

 $I_L \cong \frac{2.5 \; V}{R_S} \;\; [A] \;\; \mbox{into the load. Caution is required}$ 

since the HA17431H cathode current is also superimposed on  $I_{L}$ .

The requirement in this circuit is that the cathode current must be greater than Imin = 0.2 mA. The  $I_{L}$  setting therefore must be on the order of several mA or more.

Induction type constant current circuit  $V_{cc}$   $V_{cc}$   $V_{cc}$   $V_{cc}$   $V_{cc}$   $V_{cc}$  R  $I_{L}$   $I_{L}$   $I_{L}$  $I_{L} \cong \frac{2.5 V}{R_S}$  [A]

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## Design Guide for AC-DC SMPS (Switching Mode Power Supply)

#### Use of Shunt Regulator in Transformer Secondary Side Control

This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.



Figure 2 Typical Shunt Regulator/Error Amplifier

#### Determination of External Constants for the Shunt Regulator

**DC characteristic determination:** In figure 2,  $R_1$  and  $R_2$  are protection resistor for the light emitting diode in the photocoupler, and  $R_2$  is a bypass resistor to feed  $I_K$  minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$R_1 = \frac{V_0 - V_F - V_K}{I_F + I_B}$$
,  $R_2 = \frac{V_F}{I_B}$ 

 $V_{\rm k}$  is the HA17431H operating voltage, and is set at around 3 V, taking into account a margin for fluctuation.  $R_2$  is the current shunt resistance for the light emitting diode, in which a bias current  $I_{\rm B}$  of around 1/5  $I_{\rm F}$  flows.

Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times \text{Vref, Vref} = 2.5 \text{ V Typ}$$

The absolute values of  $R_3$  and  $R_4$  are determined by the HA17431H reference input current Iref and the AC characteristics described in the next section. The Iref value is around 0.6  $\mu$ A Typ.

**AC characteristic determination:** This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.



Figure 3 HA17431H Error Amplification Characteristic

In Figure 3, the following formulas are obtained:

Gain

 $G_1 = G_0 \approx 50 \text{ dB to } 60 \text{ dB}$  (determined by shunt regulator)

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies

$$f_1 = 1/(2\pi C_1 G_0 R_3)$$
  
$$f_2 = 1/(2\pi C_1 R_5)$$

 $G_0$  is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation  $\Delta V ref \Delta V_{KA}$ , and is approximately 50 dB.

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#### **Practical Example**

Consider the example of a photocoupler, with an internal light emitting diode  $V_F = 1.05$  V and  $I_F = 2.5$  mA, power supply output voltage  $V_2 = 5$  V, and bias resistance  $R_2$  current of approximately 1/5  $I_F$  at 0.5 mA. If the shunt regulator  $V_K = 3$  V, the following values are found.

$$R_{1} = \frac{5V - 1.05V - 3V}{2.5mA + 0.5mA} = 316(\Omega) (330\Omega \text{ from E24 series})$$
$$R_{2} = \frac{1.05V}{0.5mA} = 2.1(k\Omega) (2.2k\Omega \text{ from E24 series})$$

Next, assume that  $R_3 = R_4 = 10 \text{ k}\Omega$ . This gives a 5 V output. If  $R_5 = 3.3 \text{ k}\Omega$  and  $C_1 = 0.022 \mu\text{F}$ , the following values are found.

$$\begin{split} G_{_2} &= 3.3 \text{ k}\Omega \ / \ 10 \ \text{k}\Omega = 0.33 \ \text{times} \ (-10 \ \text{dB}) \\ f_{_1} &= 1 \ / \ (2 \times \pi \times 0.022 \ \mu\text{F} \times 316 \times 10 \ \text{k}\Omega) = 2.3 \ (\text{Hz}) \\ f_{_2} &= 1 \ / \ (2 \times \pi \times 0.022 \ \mu\text{F} \times 3.3 \ \text{k}\Omega) = 2.2 \ (\text{kHz}) \end{split}$$

#### **Package Dimensions**





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